# NSN 5961-00-468-2765

Transistor - Page 1 of 1



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#### **Inclosure Material:**

Metal

## **Overall Length:**

Between 0.250 inches and 0.340 inches

# **Overall Diameter:**

0.620 inches

## **Mounting Facility Quantity:**

2

#### Internal Configuration:

Junction contact

# Electrode Internally-electrically Connected To Case:

Collector

#### **Mounting Method:**

Unthreaded hole

Features Provided:

#### Hermetically sealed case

Semiconductor Material:

Silicon

## Voltage Rating In Volts Per Characteristic:

375.0 collector to base voltage/static/emitter open and 250.0 collector to emitter voltage/static/base open and 300.0 collector to emitter

reverse voltage and 6.0 emitter to base voltage, static, collector open

#### **Current Rating Per Characteristic:**

Between 1.00 amperes source cutoff current and 2.00 amperes source cutoff current

#### **Power Rating Per Characteristic:**

2.5 watts small-signal input power, common-collector preset

# Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

#### **Special Features:**

Junction pattern arrangement: npn

#### Test Data Document:

81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

# **Terminal Type And Quantity:**

2 uninsulated wire lead and 1 case

#### Shelf Life:

N/a

## Unit Of Measure:

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#### Demilitarization:

No

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